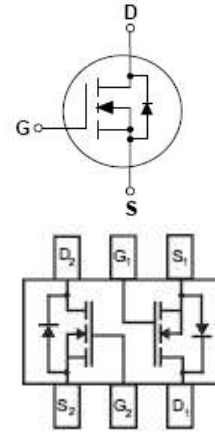


N-Channel Logic Level Enhancement Mode Field Effect Transistor

FEATURES

- Low On-Resistance.
- Low Gate Threshold Voltage.
- Low Input Capacitance.
- Fast Switching Speed.
- Low Input/Output Leakage.



SOT-363

ORDERING INFORMATION

Type No.	Marking	Package Code
BSS138DW	K38	SOT-363

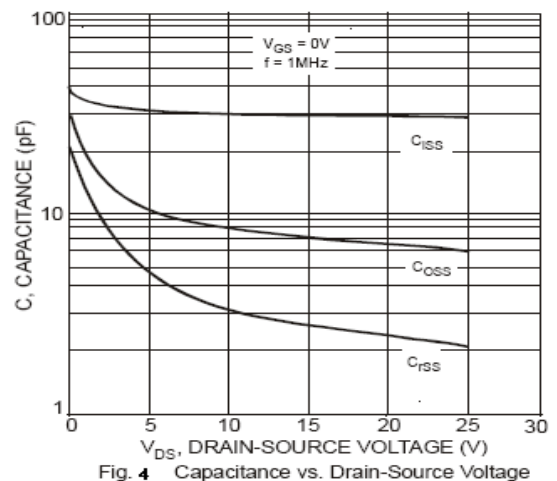
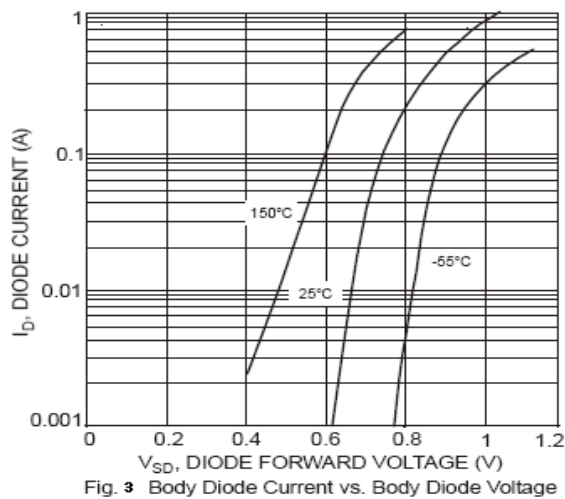
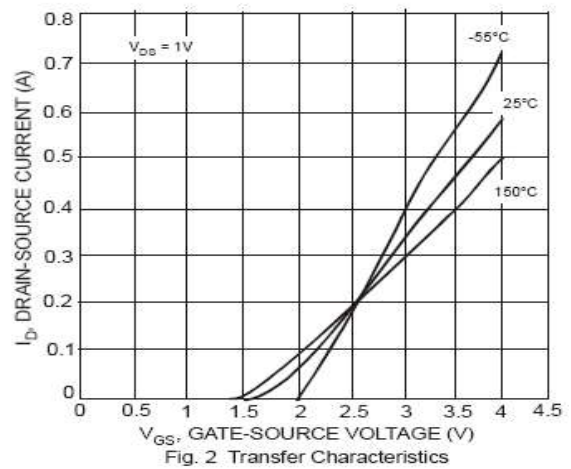
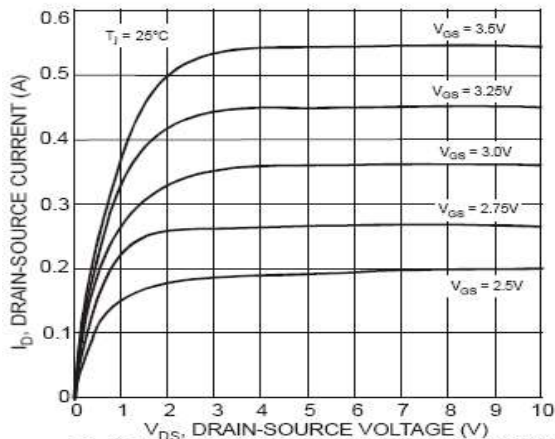
MAXIMUM RATING @ Ta=25°C unless otherwise specified

Symbol	Parameter	Value	Units
V <sub>DSS</sub>	Drain-Source voltage	50	V
V <sub>DGR</sub>	Drain-Gate voltage R <sub>GS</sub> ≤ 20K Ω	50	V
V <sub>GSS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain current -continuous	200	mA
P <sub>D</sub>	Power Dissipation	200	mW
R <sub>θJA</sub>	Thermal Resistance, Junction-to-Ambient	417	°C/W
T <sub>J</sub> , T <sub>stg</sub>	Junction and Storage Temperature	-55 to +150	°C

**ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified**

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Gate leakage current	$I_{GSS}$	$V_{GS}=\pm 20V, V_{DS}=0V$			$\pm 1$	$\mu A$
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	50	75		V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.5	1.2	1.6	V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=50V, V_{GS}=0V$			0.5	$\mu A$
Drain-source on-state resistance	$R_{DS(on)}$	$I_D=0.22A, V_{GS}=10V$		1.4	3.5	$\Omega$
Forward transfer admittance	$g_{fs}$	$V_{DS}=25V, I_D=0.2A, f=1MHz$	100			mS
Input capacitance	$C_{iss}$	$V_{DS}=10V, V_{GS}=0V, f=1.0MHz$			50	pF
Output capacitance	$C_{oss}$				25	
Reverse transfer capacitance	$C_{rss}$				8	
Turn-On Delay Time	$t_{D(ON)}$	$V_{DD} = 30V, I_D = 0.2A,$ $R_{GEN}=50\Omega$			20	ns
Turn-Off Delay Time	$t_{D(OFF)}$				20	ns

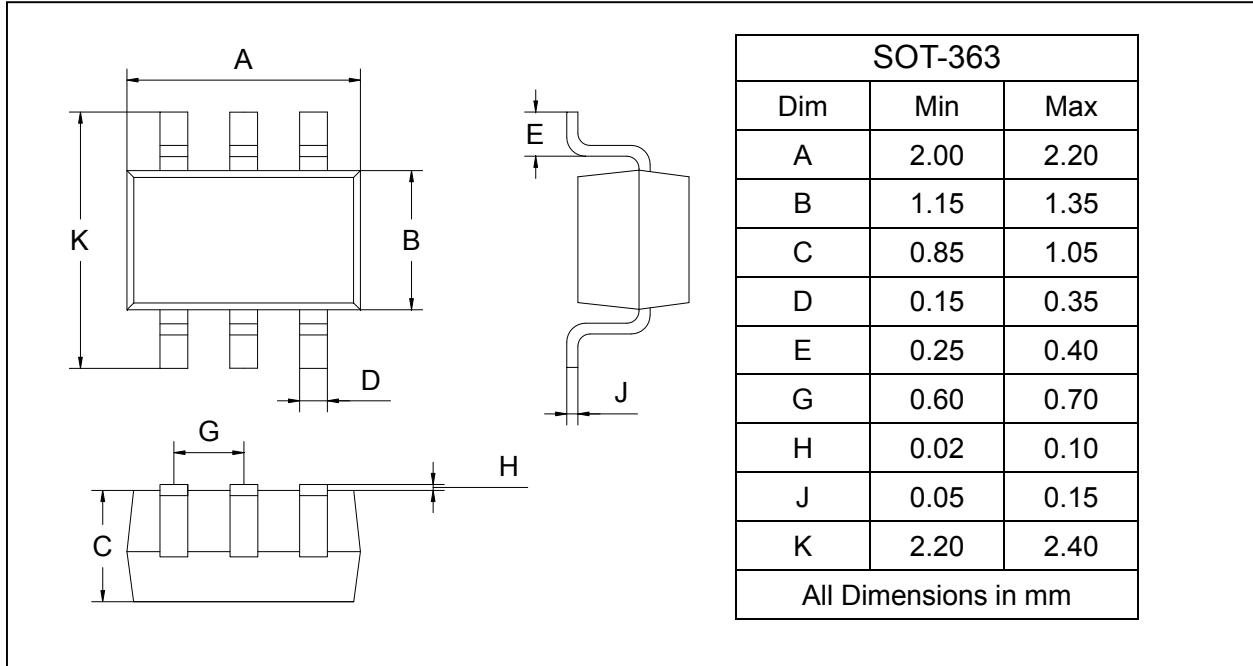
**TYPICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified**



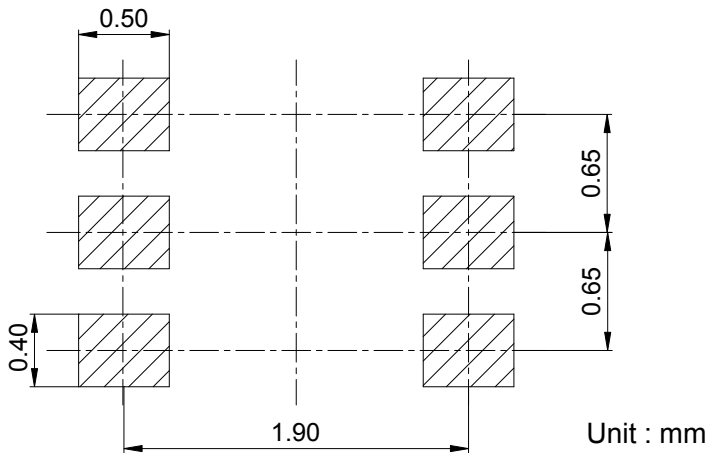
## PACKAGE OUTLINE

Plastic surface mounted package

SOT-363



## SOLDERING FOOTPRINT



## PACKAGE INFORMATION

Device	Package	Shipping
BSS138DW	SOT-363	3000/Tape&Reel

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